# NSN 5962-01-373-8315

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# Maximum Power Dissipation Rating:

1.0 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# Features Provided:

Burn in and electrostatic sensitive and programmed and ultraviolet erasable

## Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

# Input Circuit Pattern:

15 input

## Case Outline Source And Designator:

D-10 mil-m-38510

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

## Time Rating Per Chacteristic:

250.00 nanoseconds access

#### Memory Device Type:

Rom

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

28 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

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